

Benjamin A. D. Williamson

MSci, PhD, MRSC, NKS

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Employment

Norwegian University of Science and Technology (NTNU) (2019 – Present)

Trondheim, Norway

Postdoctoral Researcher in Computational Materials Design

Functional Materials and Materials Chemistry Research Group (FACET)

Advisor: Prof. Sverre M. Selbach

University College London (2018 – 2019)

London, United Kingdom

Postdoctoral Research Associate in Computational Materials Design

Scanlon Materials Theory Group

Advisor: Prof. David O. Scanlon

University Education

University College London (2014 – 2018)

London, United Kingdom

PhD in Computational Inorganic Materials Chemistry

Thesis title : *Understanding the Electronic and Thermodynamic Properties of Wide Band Gap Materials*

Supervisor: Prof. David O. Scanlon; Secondary Supervisor: Prof. Claire J. Carmalt

University College London (2010 – 2014)

London, United Kingdom

MSci in Chemistry – 1st Class Honours

MSci dissertation title: *Computational Design of Next-Generation p-Type Semiconductors*

Supervisor: Prof. David O. Scanlon

Publications

(In reverse chronological order)

1. *Experimental and theoretical study of the electronic structures of lanthanide indium perovskites LnInO_3*
P. Hartley, K.H.L. Zhang, M.V. Hohmann, L.F.J. Piper, D.J. Morgan, R.G. Edgell, D.O. Scanlon, **B.A.D. Williamson**, and A. Regoutz; *J. Phys. Chem. C*, 125, 6387, (2021)
2. *Photocatalytic, Structural and Optical Properties of Mixed Anion Solid Solutions $\text{Ba}_3\text{Sc}_{2-x}\text{In}_x\text{Cu}_2\text{S}_2$ and $\text{Ba}_3\text{In}_2\text{O}_5\text{Cu}_2\text{S}_{2-y}\text{Se}_y$*
G. Limburn, M. Stephens, **B.A.D. Williamson**, A. Iborra-Torres, D.O. Scanlon and G. Hyett; *J. Mater. Chem. A*, 8, 19887-19897 (2020)
DOI: 10.1039/D0TA06629J
3. *Computationally Driven Discovery of Layered Quinary Oxychalcogenides: Potential p-Type Transparent Conductors?*
B.A.D. Williamson, G.J. Limburn, G. Hyett, G. W. Watson and D.O. Scanlon; *Matter, Cell Press*, 3, 3, 759-781 (2020)
DOI: 10.1016/j.matt.2020.05.020

4. *Computational Prediction of the Thermoelectric Performance of LaZnOP_n (P_n = P, As)*
M. Einhorn, **B.A.D. Williamson** and D.O. Scanlon; *J. Mater. Chem. A*, 8, 7914-7924 (2020)
DOI: 10.1039/D0TA00690D
5. *Resonant Ta Doping for Enhanced Mobility in Transparent Conducting SnO₂*
B.A.D. Williamson, T.J. Featherstone, S. Sathasivam, J.E.N Swallow, H. Shiel, L.A.H. Jones, M.J. Smiles, A. Regoutz, T-L. Lee, X. Xia, C. Blackman, P.K. Thakur, C.J. Carmalt, I.P. Parkin, T.D. Veal and D.O. Scanlon; *Chem. Mater.*, 32, 5, 1964-1973 (2020)
DOI: 10.1021/acs.chemmater.9b04845
[Work featured on the front cover](#)
6. *Enhanced Photocatalytic and Antibacterial Ability of Cu-doped Anatase TiO₂ Thin Films: Theory and Experiment*
A.M. Alotaibi, **B.A.D. Williamson**, S. Sathasivam, A. Kafizas, M. Alqahtani, C. Sotelo-Vazquez, J. Buckeridge, J. Wu, S.P. Nair, D.O. Scanlon and I.P. Parkin; *ACS Appl. Mater. Interfaces* just accepted manuscripts (2020)
DOI: 10.1021/acsami.9b22056
7. *Resonant Doping for High Mobility Transparent Conductors: The Case of Mo-doped In₂O₃*
J.E.N. Swallow, **B.A.D. Williamson**, S. Sathasivam, M. Birkett, T.J. Featherstone, P.A.E. Murgatroyd, H.J. Edwards, Z.W. Lebens-Higgins, D.A. Duncan, M. Farnworth, P. Warren, N. Peng, T-L. Lee, L.F.J. Piper, A. Regoutz, C.J. Carmalt, I.P. Parkin, V.R. Dhanak, D.O. Scanlon and T.D. Veal; *Mater. Horiz.*, 7, 236-243 (2020)
DOI: 10.1039/C9MH01014A
8. *Dispelling the Myth of Passivated Codoping in TiO₂*
B.A.D. Williamson, J. Buckeridge, N.P. Chadwick, S. Sathasivam, C.J. Carmalt, I.P. Parkin and D.O. Scanlon; *Chem. Mater.*, 31 (7), 2577-2589 (2019)
DOI: 10.1021/acs.chemmater.9b00257
9. *Origin of High-Efficiency Photoelectrochemical Water Splitting on Hematite/Functional Nanohybrid Metal Oxide Overlayer Photoanode after a Low Temperature Inert Gas Annealing Treatment*
S. Ho-Kimura, **B.A.D. Williamson**, S. Sathasivam, S.J.A. Moniz, G. He, W. Luo, D.O. Scanlon, J. Tang, I.P. Parkin; *ACS Omega*, 4 (1), 1449-1459 (2019)
DOI: 10.1021/acsomega.8b02444
10. *Phosphorus Doped SnO₂ Thin Films for Transparent Conducting Oxide Applications: Synthesis, Optoelectronic Properties and Computational Models*
M.J. Powell, **B.A.D. Williamson**, S-Y. Baek, J. Manzi, D. Potter, D.O. Scanlon and C.J. Carmalt; *Chem. Sci.*, 9 (41), 7968-7980 (2018)
DOI: 10.1039/C8SC02152J
11. *Enhanced Electrical Properties of Antimony Doped Tin Oxide Thin Films Deposited via Aerosol Assisted Chemical Vapour Deposition*
S. Ponja, **B.A.D. Williamson**, S. Sathasivam, D.O. Scanlon, I.P. Parkin, C.J. Carmalt; *J. Mater. Chem. C*, 6, 7257-7266 (2018)
DOI: 10.1039/C8TC01929K
12. *A Novel Laboratory-based Hard X-ray Photoelectron Spectroscopy System*
A. Regoutz, M. Mascheck, T. Wiell, S.K. Eriksson, C. Liljenberg, K. Tetzner, **B.A.D. Williamson**, D. O. Scanlon and P. Palmgren; *Rev. Sci. Inst.*, 89 (7), 073105 (2018)
DOI: 10.1063/1.5039829

13. *Chemical Vapor Deposition of Photocatalytically Active Pure Brookite TiO₂ Thin Films*
A.M. Alotaibi, S. Sathasivam, **B.A.D. Williamson**, A. Kafizas, C. Sotelo-Vazquez, A. Taylor, D.O. Scanlon, and I.P. Parkin; *Chem. Mater.*, 30 (4), 1353-1361 (2018)
DOI: 10.1021/acs.chemmater.7b04944
14. *A Deeper Understanding of Interstitial Boron-Doped Anatase Thin Films as A Multifunctional Layer Through Theory and Experiment*
M. Quesada-Gonzalez, **B.A.D. Williamson**, C. Sotelo-Vazquez, A. Kafizas, N.D. Boscher, R. Quesada-Cabrera, D.O. Scanlon, C.J. Carmalt, I.P. Parkin; *J. Phys. Chem. C*, 122 (1), 714-726 (2018)
DOI: 10.1021/acs.jpcc.7b11142
15. *Self-Compensation in Transparent Conducting F-Doped SnO₂*
J.E.N. Swallow, **B.A.D. Williamson**, T.J. Whittles, M. Birkett, T.J. Featherstone, N. Peng, A. Abbott, M. Farnworth, K.J. Cheetham, P. Warren, D.O. Scanlon, V.R. Dhanak, T.D. Veal; *Adv. Funct. Mater.*, 1701900 (2017)
DOI: 10.1002/adfm.201701900
16. *Chemical Vapor Deposition Synthesis and Optical Properties of Nb₂O₅ Thin Films with Hybrid Functional Theoretical Insight into Band Structure and Band Gaps*
S. Sathasivam, **B.A.D. Williamson**, S.A. Al Thabaiti, A.Y. Obaid, S.N. Basahel, M. Mokhtar, D.O. Scanlon, C.J. Carmalt, I.P. Parkin; *ACS Appl. Mater. Interfaces*, 9 (21), 18031-18038 (2017)
DOI: 10.1021/acsami.7b00907
17. *Computational and Experimental Study of Ta₂O₅ Thin Films*
S. Sathasivam, **B.A.D. Williamson**, A. Kafizas, S.A. Althabaiti, A.Y. Obaid, S.N. Basahel, D.O. Scanlon, C.J. Carmalt, I.P. Parkin; *J. Phys. Chem. C*, 121 (1), 202-210 (2017)
DOI: 10.1021/acs.jpcc.6b11073
18. *Transparent Conducting n-type ZnO:Sc – Synthesis, Optoelectronic Properties and Theoretical Insight*
S.C. Dixon, S. Sathasivam, **B.A.D. Williamson**, D.O. Scanlon, C.J. Carmalt, I.P. Parkin; *J. Mater. Chem. C*, 5, 7585-7597 (2017)
DOI: 10.1039/C7TC02389H
19. *Engineering Valence Band Dispersion for High Mobility p-Type Semiconductors*
B.A.D. Williamson, J. Buckeridge, J. Brown, S. Ansbro, R.G. Palgrave, D.O. Scanlon; *Chem. Mater.*, 29 (6), 2402-2413 (2017)
DOI: 10.1021/acs.chemmater.6b03306
[Work featured as part of the front cover](#)
20. *A Single-Source Precursor Approach to Solution Processed Indium Arsenide Thin Films*
P. Marchand, S. Sathasivam, **B.A.D. Williamson**, D. Pugh, S.M. Bawaked, S.N. Basahel, A.Y. Obaid, D.O. Scanlon, I.P. Parkin, C.J. Carmalt; *J. Mater. Chem. C*, 4, 6761-6768 (2016)
DOI: 10.1039/C6TC02293F

In Submission
21. *ABWCX a Promising n-Type Thermoelectric Oxide with the DEYFZ Crystal Structure*
K.B. Spooner, A.M. Ganose, W.W.W. Leung, J. Buckeridge, **B.A.D. Williamson**, R.G. Palgrave, and D.O. Scanlon, ?, *in submission*
22. *Benchmarking the quantitative and qualitative performance of point defect calculations in semiconductors with semi-local DFT*
D. Broberg, K. Bystrom, S. Srivastava, D. Dahliah, N. Adamski, **B.A.D. Williamson**, A. Rowberg, L. Weston, M. Turiansky, D.O. Scanlon, C.G. Van de Walle, S. Dwaraknath, J.B. Varley, K. Persson, M. Asta and G. Hautier; *in submission*

23. *Resonant XX Doping for High-Mobility In₂O₃-Based Conductors with Enhanced Near-Infrared Transparency*
T. J. Featherstone, J. Willis, J.E.N. Swallow, **B.A.D. Williamson**, L.A.H. Jones, T.-Li. Lee, P.K. Thakur, G.W. Watson, T. Koida, D.O. Scanlon, and T.D. Veal; *in submission*
24. *Effect of pseudo-cubic (111)-oriented orthorhombic substrate facets on perovskite oxide thin film synthesis*
K. Kjærnes, T. Bolstad, D.M. Evans, E. Lysne, **B.A.D. Williamson**, D. Meier, S.M. Selbach, T. Tybell; *in submission*

Conference Presentations

1. Contributed: B.A.D Williamson: *Computational discovery of an earth abundant, stable Li solid electrolyte*, FACET Sustainability Workshop, Trondheim, Norway 2021 –Oral
2. Contributed: B.A.D Williamson: *Computational Insights into Li diffusion in Solid State Electrolytes*, 7th Inorganic and Materials Norsk Kjemisk Selskap (NKS) Meeting, Værnes, Norway 2020 –Oral
3. Contributed: B.A.D Williamson: *Resonant Doping for High Mobility Transparent Conductors: The Case of Mo-doped In₂O₃*, 11th Petite Workshop on defects in energy materials; Sommarøy, Norway 2019 – Oral
4. Contributed: B.A.D Williamson: *Computationally Aided Discovery of Layered Quinary Oxychalcogenide p-type Transparent Conductor*, Workshop For Atomistic Modelling; Trondheim, Norway 2019 – Poster
5. Contributed: B.A.D Williamson: *Dispelling the Myth of Passivated Codoping in TiO₂*, MRS Fall Meeting; Boston US, 2018 – Oral
6. Contributed: B.A.D.Williamson: *Computationally Aided Discovery of Layered Quinary Oxychalcogenide p-type Transparent Conductors*, MRS Fall Meeting; Boston US, 2018 – Poster
Winner of the ICDD prize for materials characterisation
7. Contributed: B.A.D Williamson: *Doubled Conductivity in Transparent Conducting In₂O₃ Through Novel Dopant Design*, MMM Hub; Thomas Young Centre, London, UK, 2018 – Poster
8. Invited: B.A.D Williamson: *Doubled Conductivity in Transparent Conducting In₂O₃ Through Novel Dopant Design*, MCC 3rd Conference, Lincoln UK, 2018 – Oral
9. Contributed: B.A.D Williamson: *Doubled Conductivity in Transparent Conducting In₂O₃ Through Novel Dopant Design*, Gordon Research Conference; Defects In Semiconductors, Colby-Sawyer College, New Hampshire, US, 2018 – Poster
10. Invited: B.A.D Williamson: *Beyond Conventional Doping in SnO₂*, Thomas Young Centre, London UK, 2017 – Oral
11. Contributed: B.A.D Williamson: *Beyond Conventional Doping in SnO₂*, E-MRS; Spring Meeting, Strasbourg France, 2017 – Poster
12. Contributed: B.A.D Williamson: *Engineering Valence Band Dispersion For High-Mobility p-type Semiconductors*, E-MRS; Spring Meeting, Strasbourg France, 2017 – Oral
13. Contributed: B.A.D Williamson: *Engineering Valence Band Dispersion For High-Mobility p-type Semiconductors*, MRS Fall Meeting; Boston US, 2016 – Poster
14. Contributed: B.A.D Williamson: *Engineering Valence Band Dispersion For High-Mobility p-type Semiconductors*, SSCG Christmas Meeting; Canterbury UK, 2015 – Poster

Industrial Collaborations

2014 – 2019: Pilkingtons NSG Group (www.pilkington.com)
2021: Equinor (www.equinor.com)

Teaching

2021: Lecturer of Masters Course "TMT4245 FUNCTIONAL MATERIALS" at NTNU
2019 – Present: Supervised 4 final year Masters research projects at NTNU
2014 – 2019: Supervised six final year MSci research projects at UCL
2014 – 2019: Demonstrated in 1st year workshops (CHEM1004)
2018 – 2019: Tutor in 1st year inorganic chemistry courses at UCL (CHEM1101 and CHEM0013)

References

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